

1. General description

AC Thyristor power switch in a SOT223 surface-mountable plastic package with self-protective capabilities against low and high energy transients

2. Features and benefits

- Common terminal on mounting base allows multiple ACTs on shared cooling pad
- Exclusive negative gate triggering
- Full cycle AC conduction
- High noise immunity
- Remote gate separates the gate driver from the effects of the load current
- Surface-mountable package
- Very sensitive gate for lowest gate trigger current
- Safe clamping of low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients

3. Applications

- Fan motor circuits
- Pump motor circuits
- Lower-power highly inductive, resistive and safety loads

4. Quick reference data

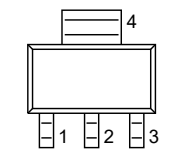
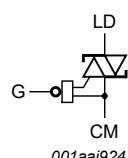
Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------------|--------------------------------------|---|-----|-----|-----|------|
| V_{DRM} | repetitive peak off-state voltage | | - | - | 600 | V |
| $I_{\text{T(RMS)}}$ | RMS on-state current | full sine wave; $T_{\text{sp}} \leq 112\text{ °C}$; Fig. 1 ; Fig. 2 ; Fig. 3 | - | - | 0.8 | A |
| I_{TSM} | non-repetitive peak on-state current | full sine wave; $T_{\text{j(init)}} = 25\text{ °C}$; $t_{\text{p}} = 16.7\text{ ms}$ | - | - | 8.8 | A |
| | | full sine wave; $T_{\text{j(init)}} = 25\text{ °C}$; $t_{\text{p}} = 20\text{ ms}$; Fig. 4 ; Fig. 5 | - | - | 8 | A |
| T_{j} | junction temperature | | - | - | 125 | °C |
| V_{PP} | peak pulse voltage | $T_{\text{j}} = 25\text{ °C}$; non-repetitive, off-state; Fig. 6 | - | - | 2 | kV |
| Static characteristics | | | | | | |
| I_{GT} | gate trigger current | $V_{\text{D}} = 12\text{ V}$; $I_{\text{T}} = 100\text{ mA}$; LD+ G-; $T_{\text{j}} = 25\text{ °C}$; Fig. 10 | 0.5 | - | 5 | mA |

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|---------------------------------------|---|------|-----|-----|------------------|
| | | $V_D = 12\text{ V}$; $I_T = 100\text{ mA}$; LD- G-; $T_j = 25\text{ }^\circ\text{C}$; Fig. 10 | 0.5 | - | 5 | mA |
| I_H | holding current | $V_D = 12\text{ V}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 12 | - | - | 20 | mA |
| V_T | on-state voltage | $I_T = 1.1\text{ A}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 13 | - | - | 1.3 | V |
| V_{CL} | clamping voltage | $I_{CL} = 0.1\text{ mA}$; $t_p = 1\text{ ms}$; $T_j \leq 125\text{ }^\circ\text{C}$; Fig. 14 | 650 | - | - | V |
| Dynamic characteristics | | | | | | |
| dV_D/dt | rate of rise of off-state voltage | $V_{DM} = 402\text{ V}$; $T_j = 125\text{ }^\circ\text{C}$; ($V_{DM} = 67\%$ of V_{DRM}); exponential waveform; gate open circuit; Fig. 15 | 300 | - | - | V/ μs |
| dI_{com}/dt | rate of change of commutating current | $V_D = 400\text{ V}$; $T_j = 125\text{ }^\circ\text{C}$; $I_{T(RMS)} = 1\text{ A}$; $dV_{com}/dt = 15\text{ V}/\mu\text{s}$; gate open circuit; Fig. 16 ; Fig. 17 | 0.15 | - | - | A/ms |

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|---|--|
| 1 | LD | load |  SC-73 (SOT223) |  001aaJ924 |
| 2 | CM | common | | |
| 3 | G | gate | | |
| 4 | CM | common | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|--------------|---------|--|---------|
| | Name | Description | Version |
| ACT108W-600D | SC-73 | plastic surface-mounted package with increased heatsink; 4 leads | SOT223 |

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|------|------------------------|
| V_{DRM} | repetitive peak off-state voltage | | - | 600 | V |
| $I_{\text{T(RMS)}}$ | RMS on-state current | full sine wave; $T_{\text{sp}} \leq 112\text{ }^{\circ}\text{C}$; Fig. 1 ; Fig. 2 ; Fig. 3 | - | 0.8 | A |
| I_{TSM} | non-repetitive peak on-state current | full sine wave; $T_{\text{j(init)}} = 25\text{ }^{\circ}\text{C}$; $t_{\text{p}} = 16.7\text{ ms}$ | - | 8.8 | A |
| | | full sine wave; $T_{\text{j(init)}} = 25\text{ }^{\circ}\text{C}$; $t_{\text{p}} = 20\text{ ms}$; Fig. 4 ; Fig. 5 | - | 8 | A |
| I^2t | I^2t for fusing | $t_{\text{p}} = 10\text{ ms}$; SIN | - | 0.32 | A^2s |
| di_{T}/dt | rate of rise of on-state current | $I_{\text{G}} = 10\text{ mA}$ | - | 50 | $\text{A}/\mu\text{s}$ |
| I_{GM} | peak gate current | $t = 20\text{ }\mu\text{s}$ | - | 1 | A |
| P_{GM} | peak gate power | | - | 2 | W |
| $P_{\text{G(AV)}}$ | average gate power | over any 20 ms period | - | 0.1 | W |
| T_{stg} | storage temperature | | -40 | 150 | $^{\circ}\text{C}$ |
| T_{j} | junction temperature | | - | 125 | $^{\circ}\text{C}$ |
| V_{PP} | peak pulse voltage | $T_{\text{j}} = 25\text{ }^{\circ}\text{C}$; non-repetitive, off-state; Fig. 6 | - | 2 | kV |

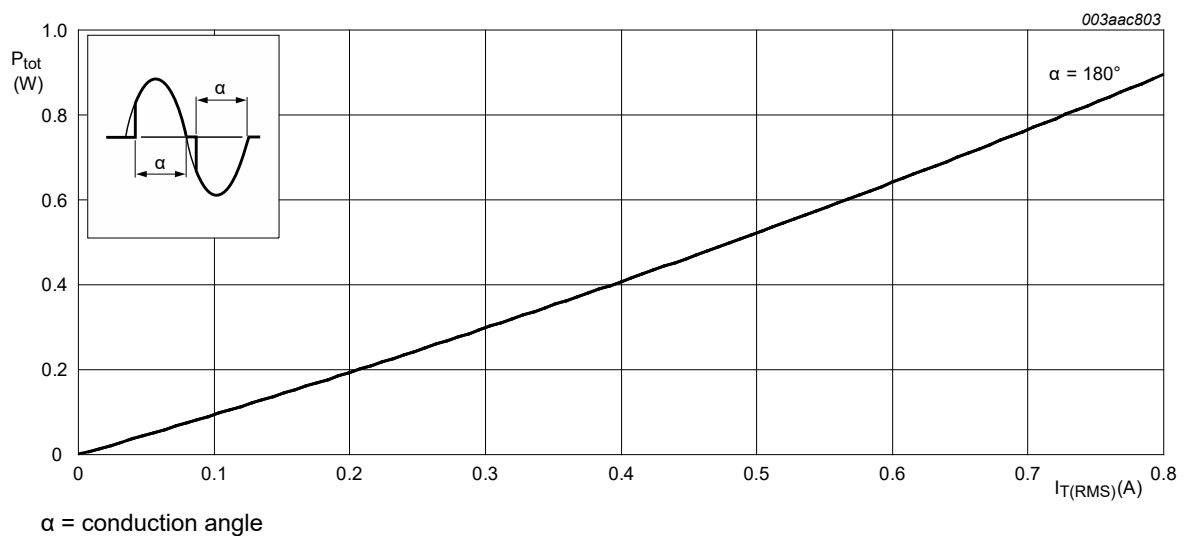


Fig. 1. Total power dissipation as a function of RMS on-state current; maximum values

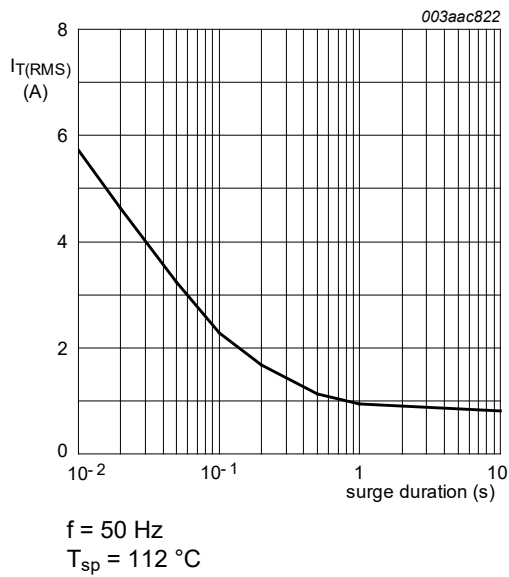


Fig. 2. RMS on-state current as a function of surge duration; maximum values

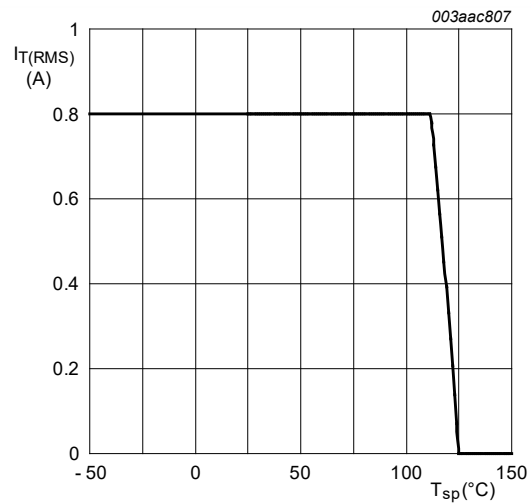


Fig. 3. RMS on-state current as a function of solder point temperature; maximum values

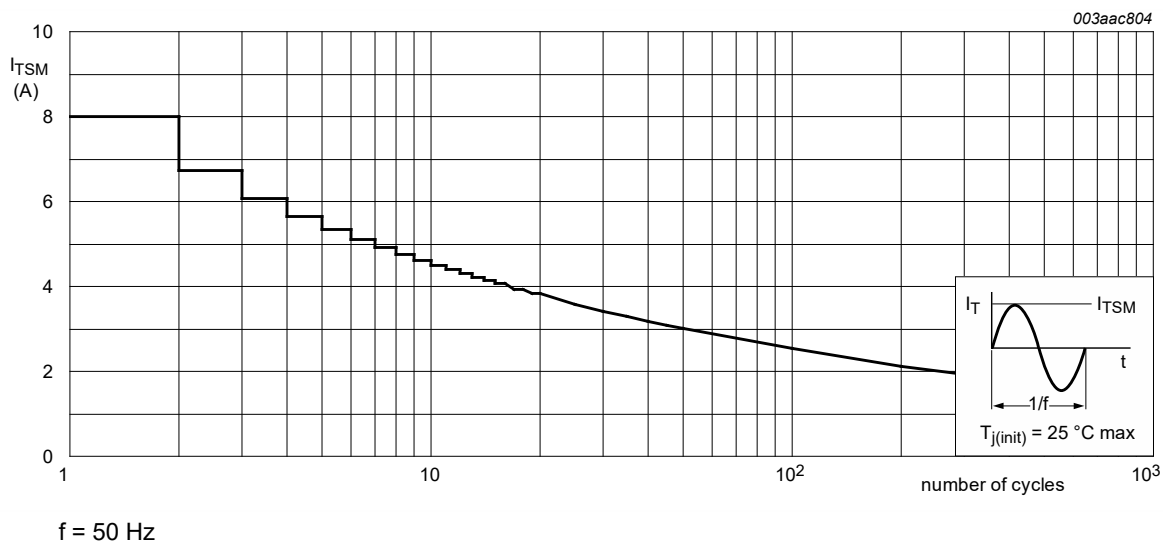


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

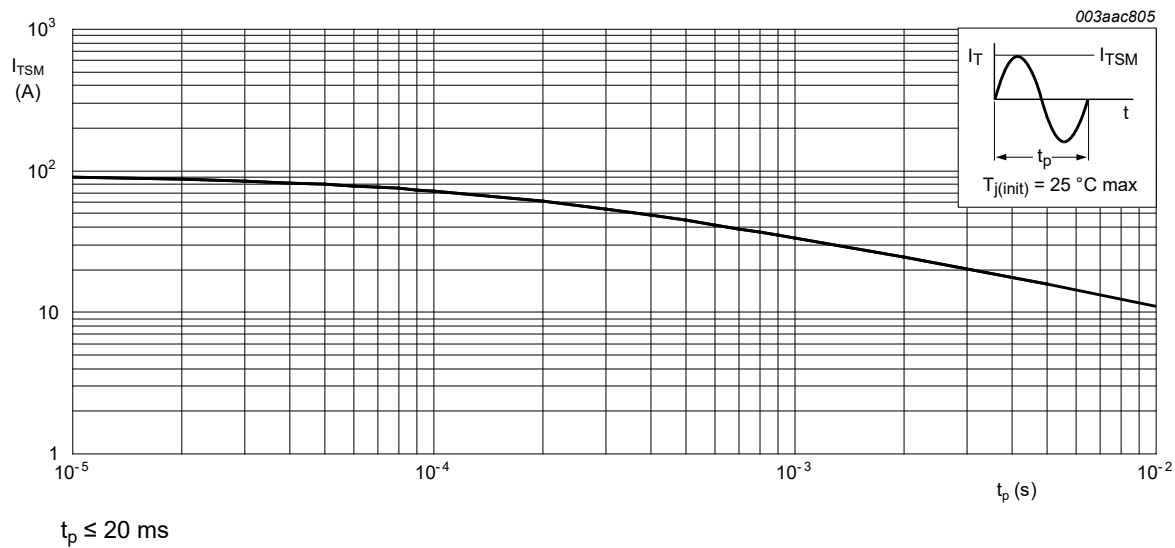


Fig. 5. Non-repetitive peak on-state current as a function of pulse width; maximum values

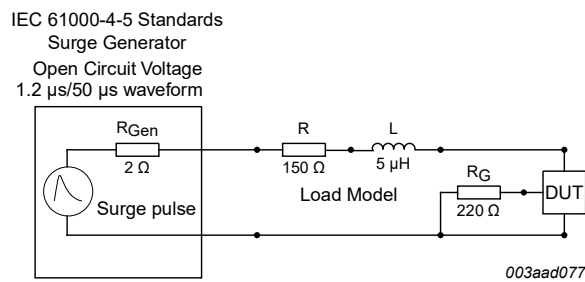


Fig. 6. Test circuit for inductive and resistive loads with conditions equivalent to IEC 61000-4-5

8. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|--|---|-----|-----|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | full cycle with heatsink compound; Fig. 7 | - | - | 15 | K/W |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient free air | in free air; printed circuit board mounted; minimum footprint; Fig. 8 | - | 156 | - | K/W |
| | | in free air; printed circuit board mounted; pad area; Fig. 9 | - | 70 | - | K/W |

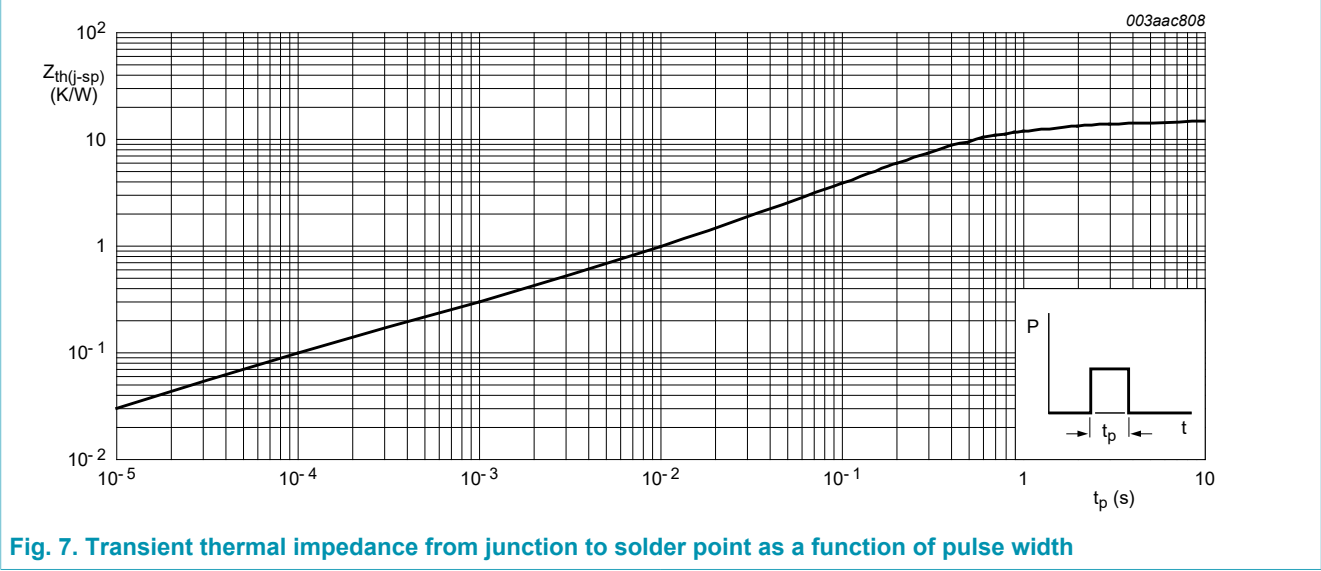
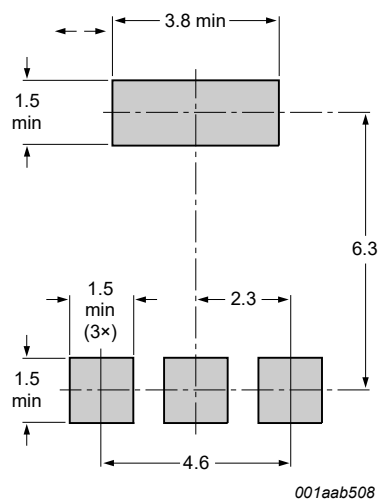
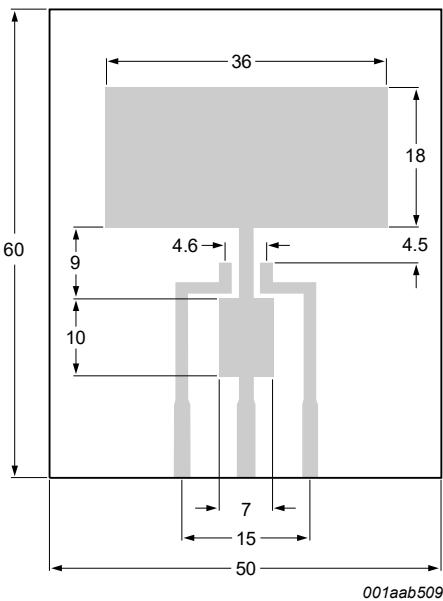


Fig. 7. Transient thermal impedance from junction to solder point as a function of pulse width



All dimensions are in mm

Fig. 8. Minimum footprint SOT223



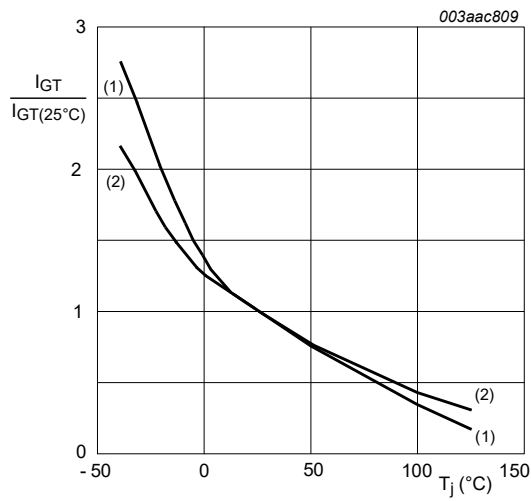
All dimensions are in mm
Printed circuit board:
FR4 epoxy glass (1.6 mm thick), copper laminate
(35 um thick)

Fig. 9. Printed circuit board pad area: SOT223

9. Characteristics

Table 6. Characteristics

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|--------------------------------|---------------------------------------|---|--|------|-----|-----|------------------|
| Static characteristics | | | | | | | |
| I_{GT} | gate trigger current | $V_D = 12\text{ V}$; $I_T = 100\text{ mA}$; LD+ G-; $T_j = 25\text{ }^\circ\text{C}$; Fig. 10 | | 0.5 | - | 5 | mA |
| | | $V_D = 12\text{ V}$; $I_T = 100\text{ mA}$; LD- G-; $T_j = 25\text{ }^\circ\text{C}$; Fig. 10 | | 0.5 | - | 5 | mA |
| I_L | latching current | $V_D = 12\text{ V}$; $I_G = 100\text{ mA}$; LD+ G-; $T_j = 25\text{ }^\circ\text{C}$; Fig. 11 | | - | - | 25 | mA |
| | | $V_D = 12\text{ V}$; $I_G = 100\text{ mA}$; LD- G-; $T_j = 25\text{ }^\circ\text{C}$; Fig. 11 | | - | - | 25 | mA |
| I_H | holding current | $V_D = 12\text{ V}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 12 | | - | - | 20 | mA |
| V_T | on-state voltage | $I_T = 1.1\text{ A}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 13 | | - | - | 1.3 | V |
| V_{GT} | gate trigger voltage | $V_D = 400\text{ V}$; $I_T = 100\text{ mA}$; $T_j = 125\text{ }^\circ\text{C}$ | | 0.15 | - | - | V |
| | | $V_D = 12\text{ V}$; $I_T = 100\text{ mA}$; $T_j = 25\text{ }^\circ\text{C}$ | | - | - | 0.9 | V |
| I_D | off-state current | $V_D = 600\text{ V}$; $T_j = 25\text{ }^\circ\text{C}$ | | - | - | 2 | μA |
| | | $V_D = 600\text{ V}$; $T_j = 125\text{ }^\circ\text{C}$ | | - | - | 0.2 | mA |
| V_{CL} | clamping voltage | $I_{CL} = 0.1\text{ mA}$; $t_p = 1\text{ ms}$; $T_j \leq 125\text{ }^\circ\text{C}$; Fig. 14 | | 650 | - | - | V |
| Dynamic characteristics | | | | | | | |
| dV_D/dt | rate of rise of off-state voltage | $V_{DM} = 402\text{ V}$; $T_j = 125\text{ }^\circ\text{C}$; ($V_{DM} = 67\%$ of V_{DRM}); exponential waveform; gate open circuit; Fig. 15 | | 300 | - | - | V/ μs |
| dI_{com}/dt | rate of change of commutating current | $V_D = 400\text{ V}$; $T_j = 125\text{ }^\circ\text{C}$; $I_{T(RMS)} = 1\text{ A}$; $dV_{com}/dt = 15\text{ V}/\mu\text{s}$; gate open circuit; Fig. 16 ; Fig. 17 | | 0.15 | - | - | A/ms |



(1) LD+ G-
(2) LD- G-

Fig. 10. Normalized gate trigger current as a function of junction temperature

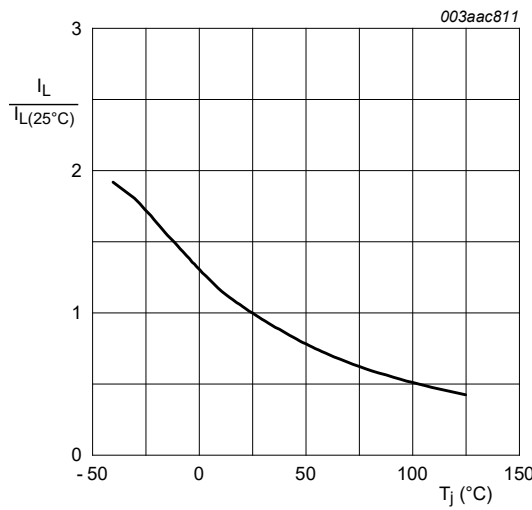


Fig. 11. Normalized latching current as a function of junction temperature

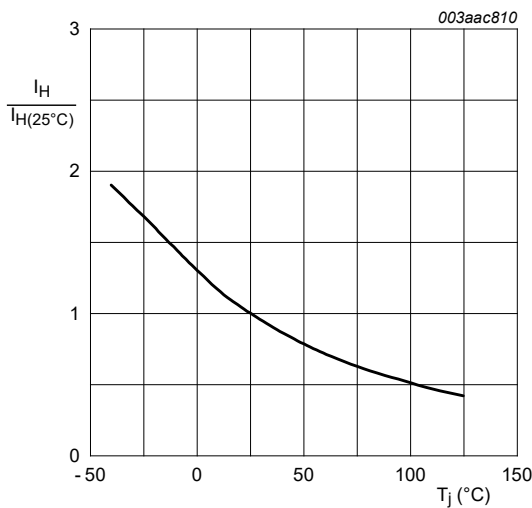
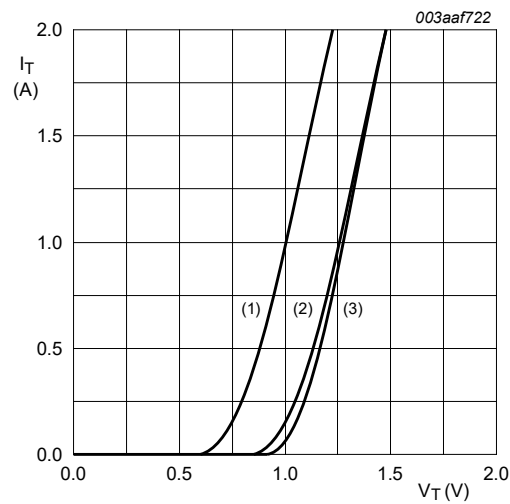
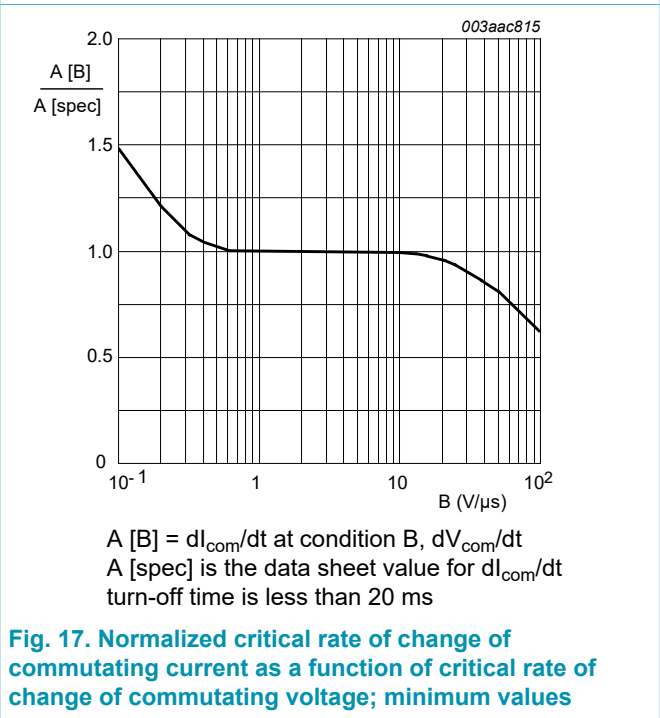
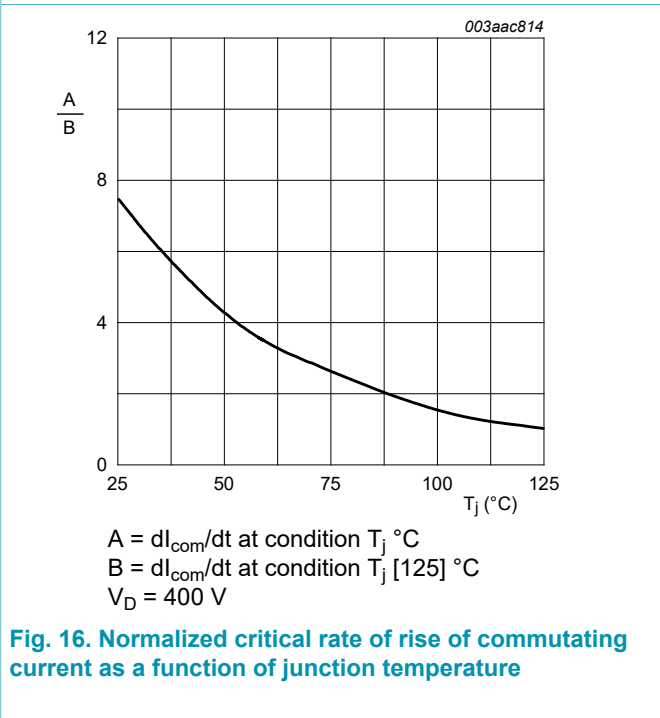
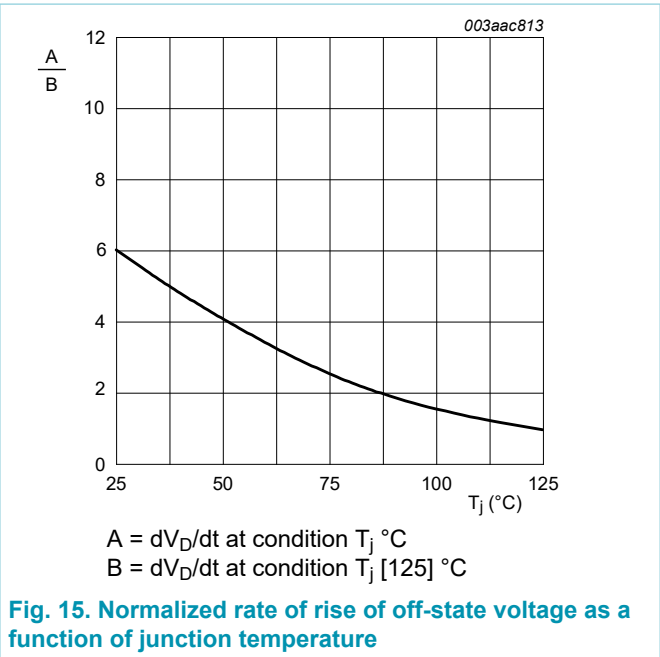
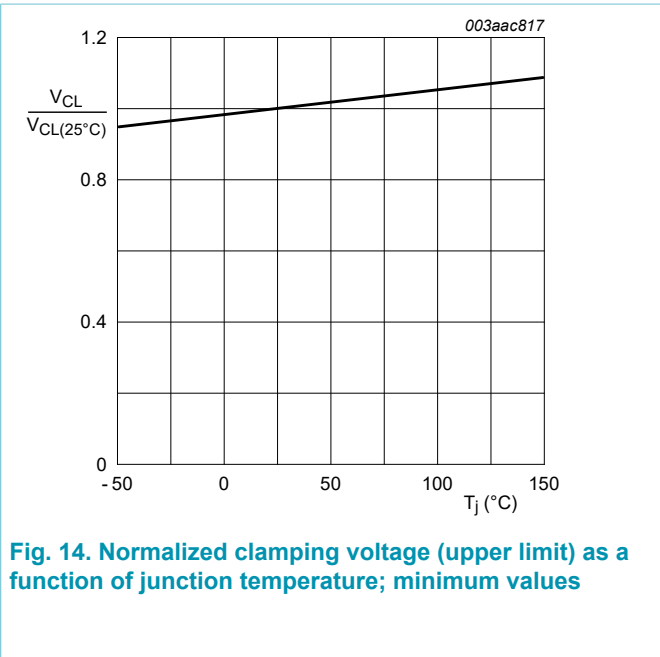


Fig. 12. Normalized holding current as a function of junction temperature

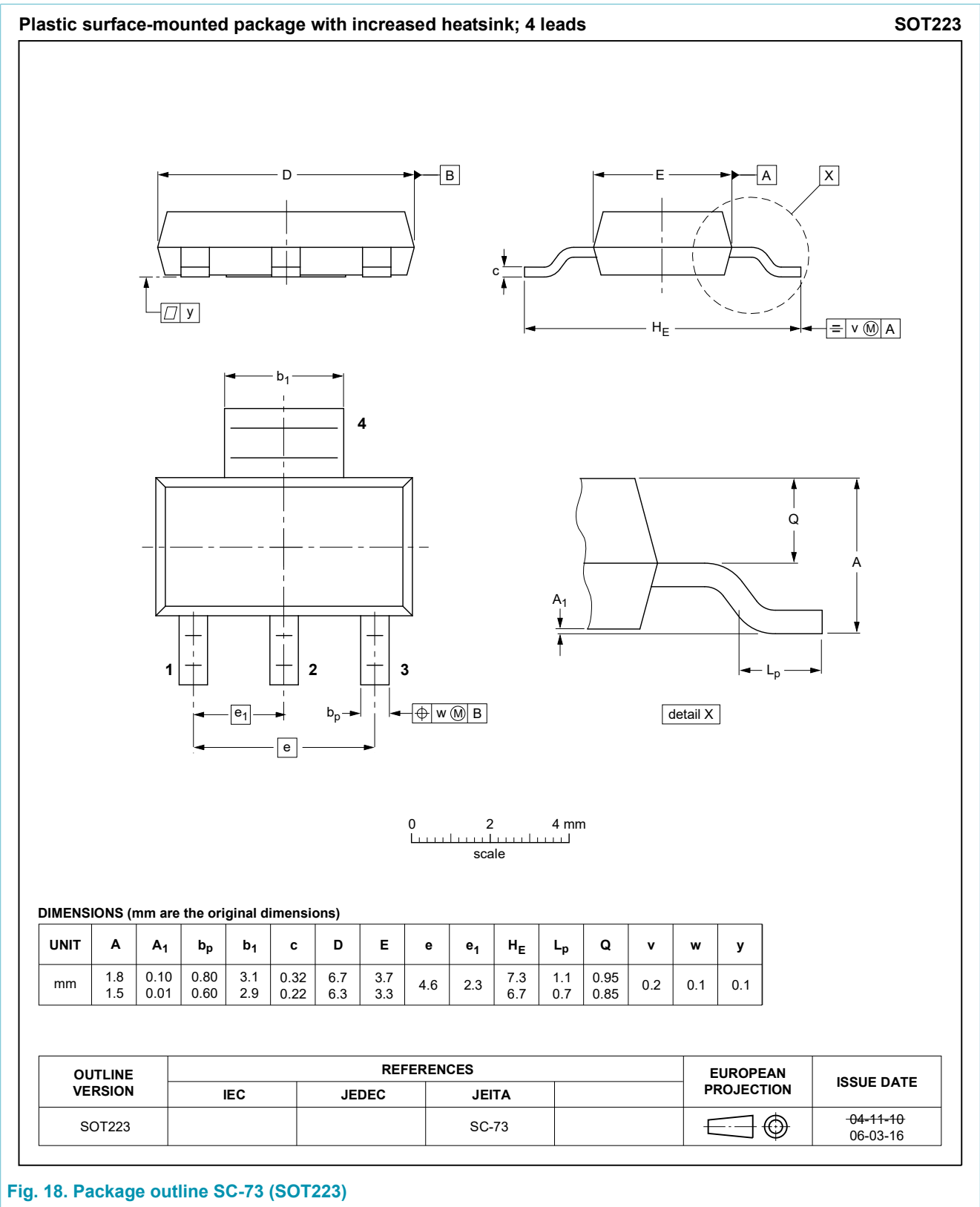


$V_o = 0.758 \text{ V}$; $R_s = 0.263 \Omega$
(1) $T_j = 125^{\circ}\text{C}$; typical values
(2) $T_j = 125^{\circ}\text{C}$; maximum values
(3) $T_j = 25^{\circ}\text{C}$; maximum values

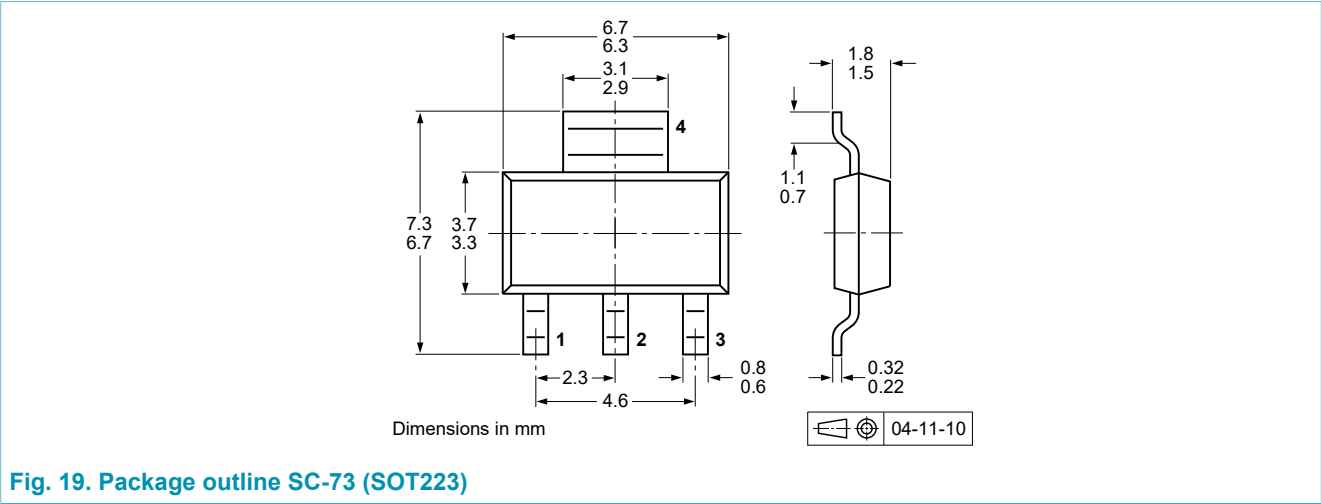
Fig. 13. On-state current as a function of on-state voltage



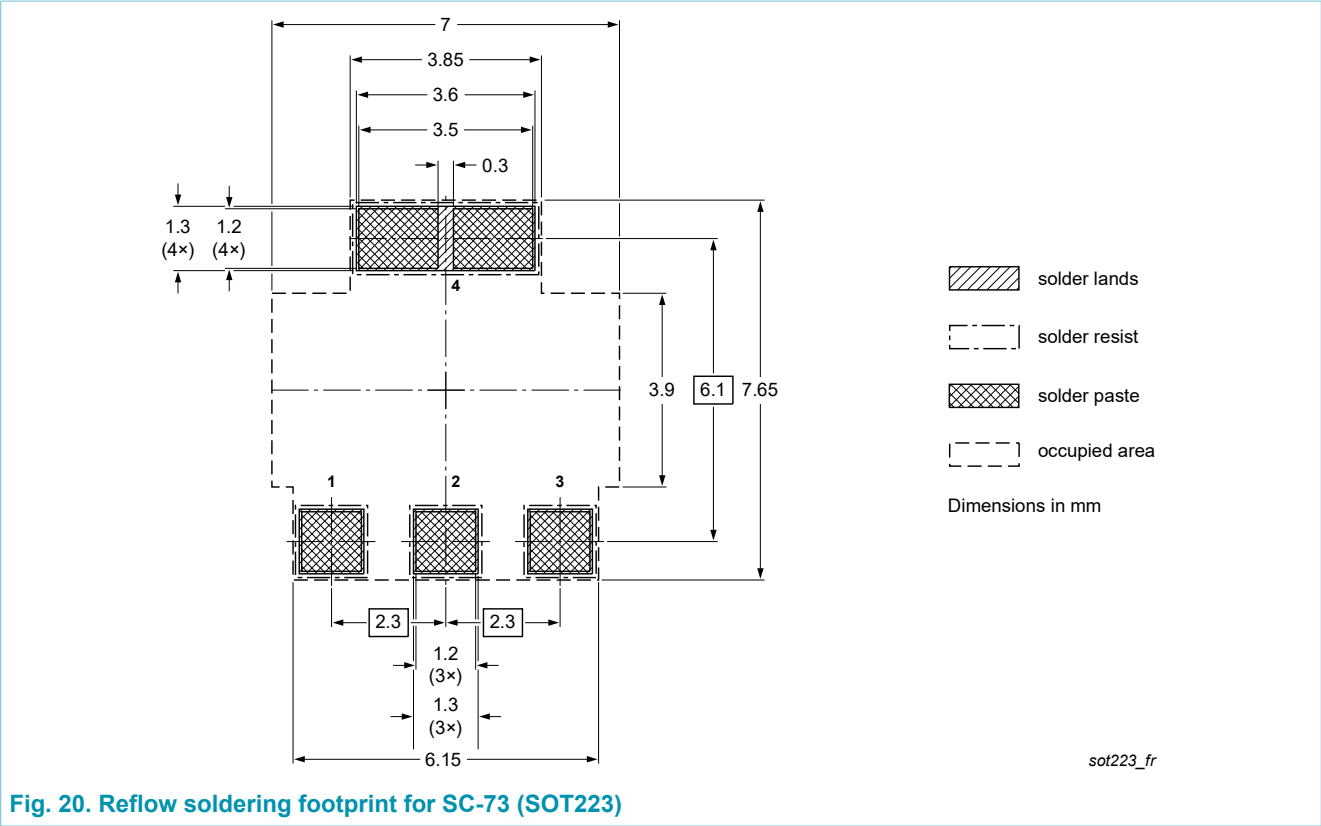
10. Package outline



11. Package outline (minimized)



12. Soldering



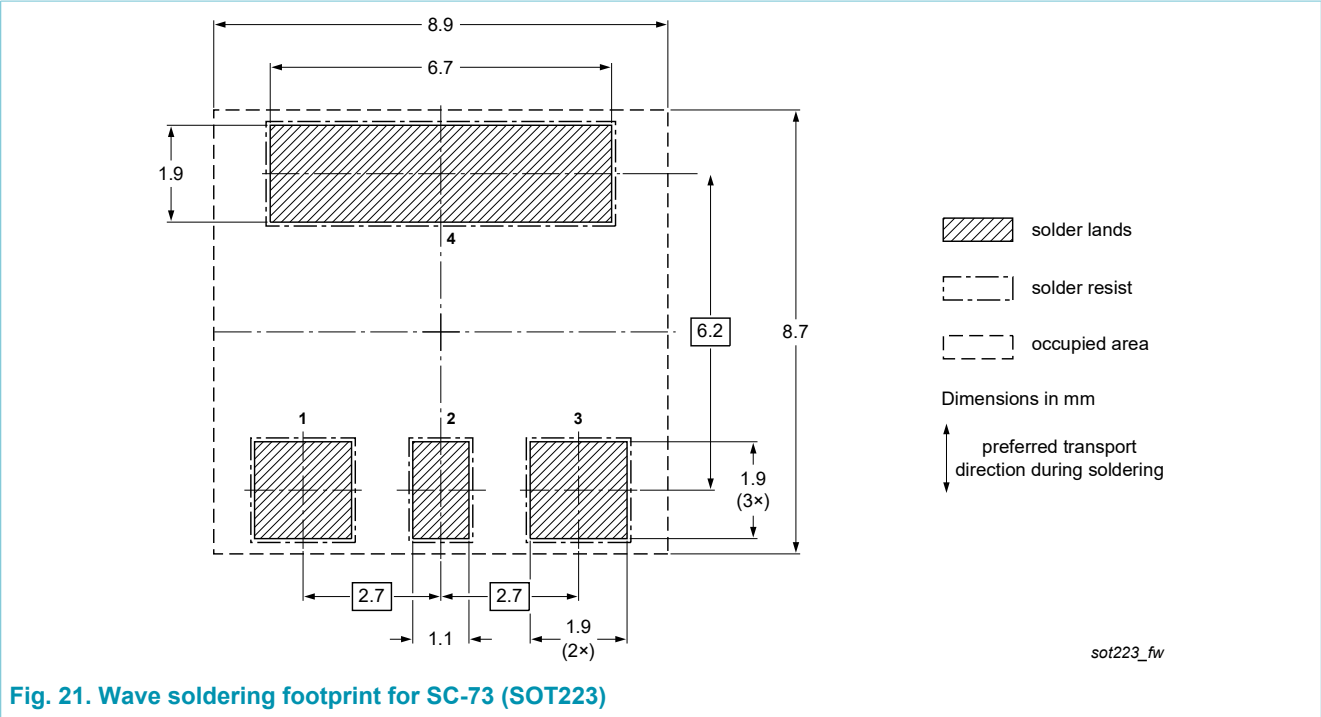


Fig. 21. Wave soldering footprint for SC-73 (SOT223)

13. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
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